Theoretical and experimental investigations on the bulk photovoltaic effect in lead-free perovskites \( \text{MAsnI}_3 \) and \( \text{FASnI}_3 \)

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Perovskite solar cells based on the lead free hybrid organic–inorganic \( \text{CH}_3\text{NH}_3\text{SnI}_3 \) (MAsnI\(_3\)) and \( \text{CH}_4\text{N}_2\text{SnI}_3 \) (FASnI\(_3\)) perovskites were fabricated, and the photovoltaic conversion efficiency (PCE) was assessed. FASnI\(_3\)'s PCE was higher than MAsnI\(_3\)'s efficiency. To study the different photovoltaic properties, we calculated their structural, electronic, and optical properties using density functional theory via the Perdew–Burke–Ernzerhof and spin–orbit coupling (PBE–SOC) methods. The results show that FASnI\(_3\) exhibits an appropriate band gap, substantial stability, marked optical properties, and significant hole and electron conductive behavior compared with MAsnI\(_3\). The interaction of organic cations (FA\(^+\)) with the inorganic framework of FASnI\(_3\) was stronger than that with MAsnI\(_3\), so they affected the band length and band angle distribution, causing the structure of the FASnI\(_3\) and MAsnI\(_3\) to change. The calculations also demonstrated that energy splitting was evident in FASnI\(_3\) due to the spin–orbit coupling effect, however, it was moderate in MAsnI\(_3\), which was caused by the H bond effect. This research not only furthers the understanding of these functional materials, but also can assist the development of highly efficient and stable non-lead perovskite solar cells.

1. Introduction

The photoelectric conversion efficiency (PCE) of organic–inorganic perovskite solar cells (PSCs) has rapidly increased from 3.8% to 25.2%. Perovskite solar cells will likely be important for the next generation of solar cells. However, an important issue must be solved for their application. The lead (Pb) in perovskite materials is toxic to the human body and environmentally unfriendly, so the preparation of lead-free perovskite solar cells has become an important problem.

Because tin (Sn) and Pb belong to the same family, they possess the same number of valence electrons. They both have two electrons in the outermost orbit, and the Sn is the first to replace the Pb in the perovskite field. Many studies have focused on MAsnI\(_3\) perovskite materials. L. J. Wu et al. calculated an energy gap of 1.3 eV, similar to the experimental results. MAsnI\(_3\) perovskite has a similar structure to MAPbI\(_3\) (although in different temperature ranges). Previous reports also indicated that MAsnI\(_3\) has a high mobility and small effective mass. However, for Sn-based perovksites, the main problem is that their efficiencies and stabilities are lower than MAPbI\(_3\) perovskite solar cells. Sn-based perovskites are sensitive to oxygen and atmospheric moisture. Therefore, the instability of MAsnI\(_3\) is related to the oxidation of Sn ion. Changing Sn\(^{2+}\) to Sn\(^{4+}\) may cause a structural transformation, reducing the photovoltaic performance of MAsnI\(_3\).

Some of research groups recently reported that when MA cation was replaced by FA cation, its band can reached 1.41 eV, and the FASnI\(_3\) had higher mobility and stability than MAsnI\(_3\). Y. Liao et al. prepared low-dimensional tin-based perovskites with PEA materials. These types of perovskite solar cells have a PCE of 5.94% after 100 h in a glovebox. Ke et al. reported that the PCE of FASnI\(_3\) reached 7.14% through 10% ethyl-enediammonium (en) doping, and the PCE was 6.37% after storing for 1000 h. Due to the high PCE and long-term stability of lead-free perovskite, using SnF\(_2\) is an effective method of producing advanced FASnI\(_3\) film. Zong et al. reported that SnF\(_2\) remained in the grain boundaries of polycrystalline films when SnF\(_2\)-3FACI was added to (FAPbI\(_3\))\(_{0.7}\)(CsSnI\(_3\))\(_{0.3}\) precursors. Under high humidity or strong light exposure, the structural phase was stable through utilizing additive, and SnF\(_2\) played a significant role in the device, but addition of excess SnF\(_2\) has also a tendency to form a separate phase on the surface of perovskite films. In addition, some literatures have analyzed the reason why the FASnI\(_3\)'s PCE was higher than the MAsnI\(_3\)'s efficiency, however, these viewpoints are more and different.

To assess the effect of replacing MA ion with FA ion, we fabricated MAsnI\(_3\) and FASnI\(_3\) solar cells and measured their PCE. We then calculated the electrical structure properties of the tetragonal phase (I4/mcm space group). We also compared...
with the differences in the optical absorption, stability, and electron and hole transport behavior of FASnI₃ and MASnI₃. We measured the antibonding coupling effect between the s orbit of Sn atoms and the p orbit of FA ions and MA ions, using first-principles calculations to elucidate the photoelectric properties of FASnI₃ and MASnI₃.

2. Experiment and calculations

2.1 Preparation of the perovskite materials

Formamidinium iodide (FASnI), methylamine iodine tin (MASnI), and SnI₂ were purchased from Sigma-Aldrich Company. The SnI₂ and FASnI (or MASnI) (1 M : 1 M) were dissolved in a solvent mixture of N,N-dimethylformamide (DMF, Sigma-Aldrich) as the precursor solution. The precursor solution was stirred at 80 °C for 12 h. The mass concentration was 30 wt% of the polymeric precursor solution. A hole transport layer was created using PEDOT:PSS (PH1000, Sigma-Aldrich) purchased from Bayer (Germany). An electron transport layer was produced using PCBM obtained from Banhe Technology Co. The SnI₂ and FASnI (or MASnI) (1 M : 1 M) were dissolved in chlorobenzene (CB, Sigma-Aldrich) and stirred at 80 °C for 6 h. ITO and silver (Ag) anodes and cathodes were used, respectively. The entire structure was ITO/PEDOT:PSS/FASnI₃(or MASnI₃)/PCBM/PEI/Ag, the device’s structure is shown in Fig. 1.

2.2 Device fabrication

First, laser-patterned, ITO-coated glass substrates were cleaned via ultrasonic oscillation in an aqueous alkaline washing solution for 15 min. Deionized water, ethanol, and acetone were used to rinse the substrates, respectively. ITO was treated with ultraviolet light in O₃ for 30 min. PEDOT:PSS was deposited by spin-coating at 5000 r.p.m. for 30 s to obtain a thickness of 40 nm. The prepared perovskite was then spin-coated on the PEDOT:PSS thin film at 1000 rpm for 10 s, followed by 4000 rpm for 35 s in a nitrogen atmosphere. The thin film was immediately annealed at 70 °C for 80 min. After cooling, PC₆₀BM (20 mg mL⁻¹) in chlorobenzene (CB, Sigma-Aldrich) and stirred at 80 °C for 6 h. ITO and silver (Ag) anodes and cathodes were used, respectively. The entire structure was ITO/PEDOT:PSS/FASnI₃(or MASnI₃)/PCBM/PEI/Ag, the device’s structure is shown in Fig. 1.

2.3 Parameter setting

For our calculations, we adopted the Vienna ab initio simulation package (VASP) based on the first-principles calculations methods. We used the projected augmented wave (PAW) method to measure the ion–electron exchange broad band energy. The plane wave basis energy cut-off was 500 eV. We used the Sn 4d5s5p, I 5s5p, C 2s2p, N 2s2p, and H 1s states as configurations. All of the atoms in these structures were allowed to relax to less than 1.0×10⁻² eV per atom. The Brillouinzone integrations were calculated using Monkhorst-Pack grids with 6 × 6 × 6 meshes. Generalized gradient approximations (GGA) combined with Perdew–Burke–Ernzerhof (PBE) functions were used for the exchange correlation. PBE significantly underestimates the band gap of halide perovskites. For example, the calculated PBE band gap is about 0.6 eV for MAPbI₃, much smaller than the experimental gap of 1.50 eV. To correct the band gap underestimation, a hybrid functional such as the Heyd–Scuseria–Ernzerhof (HSE06) functional needs to be used. The most advanced calculation approach is to use spin–orbit coupling (SOC + HSE06) calculation. However, so far, SOC + HSE06 calculations is very time consuming and can only be feasible for calculations with small unit cells. It is well known that the van der Waals (vdW) correction has an important effect on perovskite systems with weak interactions. If the effect of non-local vdW interactions on perovskite systems is neglected, then the change between the theoretical lattice constants and the experimental data is less than 1–2% when the non-local vdW function is employed. Therefore, to obtain accurate values, our calculations used a vdW correction based on the GGA-PBE method. In addition, the MAPbI₃ has a spin–orbit coupling SOC effect since it is a spin-dependent relativistic correction in origin and is more prominent in heavy elements such as Pb and Sn atoms. Even et al. reported a significant SOC effect on the band structure of Pb-based perovskite with a reduced band gap by including a large splitting of the first degenerated conduction bands.

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![Fig. 1](image-url)  (a) Device’s structure diagram, and (b) the I–V characteristics of the perovskite solar cells with the MASnI₃ and FASnI₃.
3. Results and discussion

3.1 I–V characteristics in perovskite solar cells with MASnI₃ and FASnI₃

Fig. 1 shows the current–voltage (I–V) curve characteristics of the MASnI₃ and FASnI₃ perovskite solar cells. The PCE of the FASnI₃ perovskite solar cell is greater than that of the MASnI₃. The PCE reached a maximum of 5.51%. Table 1 shows that the greater PCE in the FASnI₃ was mainly due to the rapidly increased short-circuit current (Jsc). Compared with the MASnI₃, the Jsc was only 12.47 mA cm⁻² when the FA cation replaced the MA cation. The Jsc increased quickly, and the maximum of Jsc was 15.36 mA cm⁻². This demonstrated that the interior charge transport properties increased after the FA cation replaced the MA cation. We think the effect come from the spin–orbit coupling effect, because the effect of spin–orbit coupling is different on the MASnI₃ and FASnI₃, when the light field interacts with the electrons, they generate the polarization field is also different, thus increasing the photocurrent density and the short circuit current in the solar cell, thus improving the PCE of the solar cell. In addition, under the same conditions, the open-circuit voltage ( Voc) of FASnI₃ was bigger than the MASnI₃, the Voc of FASnI₃ solar cell was 0.64 V, and the Voc of MASnI₃ was 0.57 V. In our experiment, we found that the Voc was high in the FASnI₃ without SnF₂, we thought it came from the effect of the perovskite thin film morphology, because addition of SnF₂ has a tendency to form a separate phase on the surface of perovskite films, it is not good for the morphology, it will produce a charge accumulation, the thin film morphology of FASnI₃ without SnF₂ is better than the thin film with SnF₂, it reduced the charge accumulation at interface, and reduced background carrier density, which causes the recombination loss.

3.2 Structures and formation energies

Fig. 2 shows the stable geometries after optimization. In the MASnI₃ and FASnI₃ systems, six I atoms surrounded the Sn atoms. Two I atoms are located in the apical direction and the other four in the equatorial direction. MA⁺ or FA⁺ ions filled in the octahedral cages, as demonstrated in Fig. 2. It had distorted geometries. The distortion degree of the FASnI₃ was greater than that of the MASnI₃ perovskite, which may have been caused by the high ionic conductivity properties, the ionic conductivity properties induce the distortion degree of perovskite main reason was the ion’s accumulation effect, it can produce a strong built-in electrical field in the MASnI₃ and FASnI₃ bulk, at the same time, it bring an strong polarization effect, the polarization effect can change the interaction force between molecule and molecule, thus bring the structure change of single crystal, the change of crystal structure induce the distortion degree of perovskite. The optimized lattice constants and available MASnI₃ and FASnI₃ experimental data are shown in Table 2. There were large volume contractions of 1031.86 Å³ to 971.20 Å³ from FA⁺ to MA⁺. Specifically, the lattice constriction changed along a and c directions, which was caused by the reduction in the organic framework ion radii.

In the b direction, the lattice structure had an elongation trend when the organic ion changed from MA⁺ to FA⁺, which was caused by the weak ionic bond interaction between the I ions and H ions. The angular values of α, β, and γ deviated from 90°, which was caused by structural deformations. The lattice parameters calculated using the PBE + SOC method were in good agreement with experimental data provided by D. B. Mitzi and K. Liang et al., with a deviation of 1–2%. The bond lengths and angles of the MASnI₃ and FASnI₃ systems were calculated as shown in Table 3. Table 3 demonstrates that the minimum bond length of the H-C bond (bond length of C–I bond) was larger than that of the H-C (bond length of N–I bond), which indicates that the H–N atom in the organic cation (FA⁺ and MA⁺) was closer to the Sn–I chain than the H–C atom. The H–N atom had a stronger attraction to the halogen atom by vdW forces because the H–N atom had a larger dipole moment than the H–C atom. It was obvious that the hydrogen bond between the organic cation and the inorganic framework had a considerable effect on the geometry of the investigated systems (in this paper, the hydrogen bond is defined as the bond length between the ammonium hydrogen atoms and the halogen atoms with a value less than 2.8 Å). Compared with the FASnI₃ and MASnI₃ systems, the interaction effect of the FA⁺ organic cation and the inorganic framework was stronger in the

| Table 1 Photovoltaics performance of the MASnI₃ and FASnI₃ materials |
|------------------|------------------|------------------|------------------|
| **Materials** | **Voc (V)** | **Jsc (mA cm⁻²)** | **FF** | **PCE (%)** |
| MASnI₃ | 0.57 | 12.47 | 0.44 | 3.13 |
| FASnI₃ | 0.64 | 15.36 | 0.56 | 5.51 |
FASnI$_3$ than in the MASnI$_3$, so it affected the bond length and bond angle’s distribution, changing the structure of the FASnI$_3$ and MASnI$_3$. The bond lengths of the Sn–I in both the equatorial and apical directions had a similar trend to the lattice parameters. The average Sn–I bond lengths were 3.13 Å and 3.25 Å for the MASnI$_3$ and FASnI$_3$, respectively. Both the bond lengths and the angles of the Sn–I were significantly affected by the distribution of the MA$^+$ and FA$^+$.

The stability of MASnI$_3$ and FASnI$_3$ perovskites is the bottleneck question for the development of perovskite solar cell applications. The stability can be estimated from the formation energy. Based on the UV-vis spectra and the X-ray photoelectron spectroscopy results, and the formation energy was expressed using the following equations:

$$E_f = E(MASnI_3) - E(MAI) - E(SnI_2)$$

where $E_f$ is the formation energy and $E(MASnI_3)$, $E(FASnI_3)$, $E(MAI)$, $E(FAI)$, and $E(SnI_2)$ are the corresponding total energies obtained using the PBE + SOC calculations. The calculated formation energies of the perovskites are shown in Fig. 3.

According to the aforementioned definition, a negative $E_f$ corresponds to a stable geometry, and the more negative, the more stable. Thus, the stability order of the three perovskites was MAPbI$_3$ > FASnI$_3$ > MASnI$_3$ by the formation energy.

Here, we discussed the stability only from the atom structure in the microstructure, and not discussed the stability on the macro-level. The crystal is regarded as a perfect crystal in the ideal state, which is different from the macroscopic stability. We think the internal atom structure certainly will affect the perovskite materials to the influence of external environment. MAPbI$_3$ and FASnI$_3$ had little difference in their formation energy values, indicating that the FASnI$_3$ had a similar stability to the MAPbI$_3$. Based on the analysis of the structural properties and formation energies of the MASnI$_3$ and FASnI$_3$ systems, it was clear that weak interactions between the cation FA$^+$ framework had an important effect on determining the equilibrium structures and stabilities of the perovskites.

### 3.3 Electronic properties and effective mass

To provide a rationale for the observed band-gap and spectral variation, we investigated both structural. The energy band structure is an important factor for determining many physical

Table 2 | Calculated lattice parameters of the MASnI$_3$ and FASnI$_3$ perovskites using the PBE + SOC method

<table>
<thead>
<tr>
<th>Type</th>
<th>$a$</th>
<th>$b$</th>
<th>$c$</th>
<th>$\alpha$</th>
<th>$\beta$</th>
<th>$\gamma$</th>
<th>$V/\text{Å}^3$</th>
</tr>
</thead>
<tbody>
<tr>
<td>MASnI$_3$</td>
<td>8.73</td>
<td>8.95</td>
<td>12.43</td>
<td>90.05</td>
<td>90.01</td>
<td>89.97</td>
<td>971.20</td>
</tr>
<tr>
<td>MASnI$_3$ (exp.$^a$)</td>
<td>8.82</td>
<td>8.82</td>
<td>12.56</td>
<td>90</td>
<td>90</td>
<td>977.07</td>
<td></td>
</tr>
<tr>
<td>FASnI$_3$</td>
<td>8.89</td>
<td>9.19</td>
<td>12.63</td>
<td>90.16</td>
<td>90.12</td>
<td>88.07</td>
<td>1031.86</td>
</tr>
<tr>
<td>FASnI$_3$ (exp.$^b$)</td>
<td>9.04</td>
<td>9.04</td>
<td>12.71</td>
<td>90</td>
<td>90</td>
<td>1038.68</td>
<td></td>
</tr>
</tbody>
</table>

$^a$ From ref. 27. $^b$ From ref. 28.

Table 3 | Calculated ranges of the bond lengths and bond angles of the MASnI$_3$ and FASnI$_3$ systems using the PBE + SOC method

<table>
<thead>
<tr>
<th>Type</th>
<th>MASnI$_3$</th>
<th>FASnI$_3$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$H_{N-I}$</td>
<td>2.61–3.53</td>
<td>2.81–3.73</td>
</tr>
<tr>
<td>$H_{C-I}$</td>
<td>3.23–3.46</td>
<td>3.32–3.69</td>
</tr>
<tr>
<td>Sn–I (equatorial)</td>
<td>2.82–3.64</td>
<td>3.17–3.24</td>
</tr>
<tr>
<td>Sn–I2 (apical)</td>
<td>2.82–3.63</td>
<td>3.17–3.25</td>
</tr>
<tr>
<td>Sn–I–Sn (equatorial)</td>
<td>153–167</td>
<td>150–170</td>
</tr>
<tr>
<td>Sn–I–Sn (apical)</td>
<td>167–168</td>
<td>170–178</td>
</tr>
</tbody>
</table>
properties such as absorption, photoconductivity, and electroluminescence. Fig. 4 shows the energy band structure of the MASnI3 and FASnI3 calculated using the PBE + SOC methods. The band gap of the MASnI3 obtained using the PBE + SOC method was 0.882 eV, which did not match well with the experimental result of 1.30 eV. The band gap of the FASnI3 calculated using the PBE + SOC method was 0.868 eV, lower than the previous experimental result of 1.41 eV because the PBE calculation used many approximate treatments to under-rate the band gap. A SOC calculation performed for MASnI3 and FASnI3 at the geometry and cell parameters, while rescaling the MASnI3 and FASnI3 coordinates to the experimental MASnI3 and FASnI3 cell parameters, led to a 0.42 eV and a 0.55 eV band-gap decrease compared to MASnI3 and FASnI3, respectively, as estimated by PBE + SOC. This data suggests that out of the 0.42 eV and a 0.55 eV calculated band-gap difference, ~0.2 eV are due to SOC effect, such as the different degree of tilting of the MI6 octahedra by the SOC effect, usually, the SOC calculation can under-rate the band gap. SOC + HSE06 calculation is very time consuming and can only be feasible for calculations with small unit cells. In our study, most calculations require the use of large super cells. For these calculations, it is not possible to consider SOC + HSE06 or SOC – GW. Therefore, here we select the van der Waals (vdW) correction + PBE + SOC to the calculate of optical properties and electron and hole transport behavior of MASnI3 and FASnI3.

For the spin–orbit coupling effects, the SOC had a dramatic effect on the conduction band region, with a sharp reduction in the bottom of the conduction band. This reduction was caused by the splitting of the conduction band into a two-fold degenerated state |1/2, ±1/2⟩ corresponding to light electrons and four-fold degenerated states |3/2, ±3/2⟩, |3/2, ±1/2⟩ corresponding to heavy electrons at the G point. It follows that the bands gaps decreased to 0.882 eV in the MASnI3 and 0.868 eV in the FASnI3, much lower than the experimental results of MASnI3 1.30 eV and FASnI3 1.41 eV. This means that the SOC had a rather strong energy-splitting effect on the band structure of the MASnI3 and FASnI3 perovskites. Comparing Fig. 4 (a) and (b), the SOC had a dramatic effect on the conduction band region with a sharp reduction in the bottom of the conduction band in the FASnI3. Fig. 4(a) clearly shows that the bands of the MASnI3’s CBM and CBM + 1 (we defined the first and the second bands from the bottom of the conduction bands as CBM and CBM + 1, respectively) began to split into two bands along the Y to R directions, but both bands over lapped again in the region near the Z point. However, in the FASnI3 energy band calculated using the SOC effect (see Fig. 4(b)), both the CBM and CBM + 1 had two isolated bands along the G to Y directions after the energy splitting, and the CBM still had a single line after the influence of the SOC effect. We speculate that the SOC had a strong effect in the FASnI3. We will discuss how the SOC affected the valence bands in the density of state section.
Since the photo-generated electrons and holes in the perovskites thermally relaxed to the CBM and VBM, respectively, a small effective mass facilitated the transportation of the electrons and holes. The effective masses of the $m^*_e$ and $m^*_h$ were calculated via the following equation:

$$m^* = h^2 \left[ \frac{\partial^2 \epsilon(k)}{\partial k^2} \right]^{-1},$$

(5)

where $\epsilon(k)$ is the band edge eigenvalue and $k$ is the wave vector. Different calculation methods gave varying band structures, and diverse band volatility appeared along the high symmetry directions of the Brillouin zone. This also led to sizable differences in the calculated effective masses of the electrons and holes as derived by parabolic band fitting around the G to R directions of the Brillouin zone. These effective masses (G to R directions) are listed in Table 4. We also compared the calculated reduced masses $\mu = m_e m_h / (m_e + m_h)$ with experimental data for the MASnI$_3$ in a range of 0.3–0.45 $m_0$ ($m_0$ was the electron static mass). Thus, the calculated $\mu$ values for the two objects matched the experimental value range. In the actual crystal, there were several elastic scatterings caused by photons and structural defects and impurities that increased the effective masses, so the estimated effective masses were obtained by minimizing these scatterings in the perovskite crystals. These electron and hole effective masses were slightly smaller than those of measured semiconductors used in photovoltaic cell.

The effective masses of the MASnI$_3$ and FASnI$_3$ calculated using the PBE-SOC methods agreed well with previous reports. Thus, in terms of the FASnI$_3$, broadly speaking, it had better electron and hole transport than the MASnI$_3$ under similar conditions, so it can be considered a good choice to substitute for MASnI$_3$.

To further understand the electronic structures of the two perovskites, the density of states were analyzed. The DOS structures obtained using the SOC calculations are shown in Fig. 5. The projected density of states (PDOS) in Fig. 5 reflected the calculation of the PBE-SOC structures. The peak intensities of their PDOS with the SOC effect were weak, which are barely visible in Fig. 5. Comparing the partial density of states (PDOS) of the MASnI$_3$ and FASnI$_3$ structures, a shift in the SOC-PDOS was reflected in the region near the zero point showing a shrunken band gap. This phenomenon was more obvious in the FASnI$_3$, in which both the valence bands and conduction bands shifted toward the zero point. The FASnI$_3$ had a larger spin–orbit coupling constant than the MASnI$_3$. Both structures had two peaks in the valence band maximum (VBM). The peak intensities of the MASnI$_3$ were weaker than those of the FASnI$_3$ as obtained using the PBE + SOC calculation. The SOC also may have caused the weak energy splitting in the VBM. As shown in Fig. 5, the main contribution to the VBM was from the 5p orbitals of the I atoms with an overlap in the s orbitals of the Sn atoms, while the CBM was dominated by the p orbitals of the Sn atoms partly hybridized with the I orbitals. The MA’ and FA’ cations also contributed slightly to the CBM and VBM around the Fermi energy level ($E_{\text{Fermi}}$ was adjusted to the zero point).

In the Partial Density of States (PDOS) in the FASnI$_3$ perovskites, the SOC results showed a strong shift on the VBM edges. The peak splitting in the valence bands of the FASnI$_3$ was not similar to those in the MASnI$_3$. However, the SOC-PDOS of the FASnI$_3$ showed a complete overlap with the PDOS using the SOC correction. This means that the SOC also caused strong energy splitting in the valence bands, confirming the conclusion drawn from the FASnI$_3$ results. More importantly, the different degrees of peak splitting in the valence bands also indicated that the SOC had some effects on the interaction between the organic cations (FA’ and MA’) and H bonds. The main contributions to the VBM were from the p orbitals in the C atoms, with an overlap in the s orbitals of the H atoms. These features can be seen in the charge densities of the VBM shown in the left and right panels of Fig. 6. FASnI$_3$ is used as an example with more details. The green iso surfaces in the VBM were distributed in the 5p orbitals of the I and s orbitals of FA ions, while in the CBM, they were with the 4p orbitals in the Sn. This means that the electrons were distributed around the CBM and the holes were around the VBM. These results demonstrate that the electrons and holes separated effectively between the CBM and VBM since the electrons on the 5p orbitals of the I and the 4s orbitals of the Sn were excited to the 4p orbitals of the Sn under photoexcitation. Both the total charge density of the MASnI$_3$ shown in the left panel of Fig. 6(a) and the PDOS in Fig. 5 indicate that the charge accumulated in the region between the I atoms and MA’ matrix, confirming the formation of the H–I hydrogen bonds. A similar situation also occurred in the FASnI$_3$, as shown in Fig. 6(b). To better elucidate the coupling between the MA’ and FA’ and the Sn–I chain, contour plots of the electrostatic potential were drawn for specific surfaces as shown in Fig. 7(a and b). The coupling action was weak since there was no many electrons orbital overlap between the cation MA’ and FA’ and the I atoms. This means that there was not a strong covalent interaction between the organic molecules and the I atoms. But there were strong overlaps between the Sn and I atoms, demonstrating the strong covalent bonding in the Sn–I chains. The weak contour lines between the H and I also indicated that a weak interaction occurred between the two types of atoms, forming an H–I hydrogen bond. The electrostatic potential of the VBM was mainly the anti-bonding component of the hybridization between the s orbitals of the Sn and the p orbitals of the I, while the CBM was almost a non-bonding state dominated by the p orbitals of the Sn.

For more insight into the electron distribution on the bands near the VBMs and CBMs of the MASnI$_3$ and FASnI$_3$, the charge difference densities are displayed in Fig. 7. The charged is tribution was primarily located in the Sn and I atoms, and the electron density increased as the valence bands increased in the FASnI$_3$. Compared with the MASnI$_3$, the densities of the FASnI$_3$...
accumulated around the p orbitals of the Sn atoms with little difference as the band energy changed, indicating that the electrons moved from the valence bands to the conduction bands, filling the holes with VBMs. As for the appropriate band gap between the CBM and VBM, it caused the electrons to inject into the conduction bands, thus increasing the photovoltaic efficiency.

### 3.4 Optical properties

Fig. 8 shows the optical absorption coefficients of the MASnI$_3$ and FASnI$_3$ calculated using the equation $A(\omega) = 1 - e^{-\omega^{\Delta\varepsilon}}.$ This result agrees well with those of Feng et al. using the TDDFT method. As shown in Fig. 8(a), the FASnI$_3$ had the strongest absorption in the entire visible solar spectrum, and the spectrum of MASnI$_3$ showed a blue shift with respect to the FASnI$_3$, the FASnI$_3$ had a large red shift, and the coefficient was better than the MASnI$_3$. Unlike the MAPbI$_3$, the MASnI$_3$ and FASnI$_3$ had weak absorption in the ultraviolet spectrum, also agreeing with the previously discussed trend in the band gap. For the absorption spectrum of the MASnI$_3$ and FASnI$_3$ perovskites in the visible light region, the FASnI$_3$ absorption coefficient was better than that of the MASnI$_3$. According to the absorption spectra of the FASnI$_3$ in ref. 49, it has an absorption of 2.0–
4.0 eV in the 310–620 nm spectrum region, the same trend as our results. The absorption of the FASnI$_3$ was in good agreement with the experimental results. To further study the solar energy-harvesting properties, we calculated the dielectric function of the two perovskites. The real and imaginary parts of the dielectric function are shown in Fig. 8(b). For the computed structures, the dielectric spectra in the imaginary parts demonstrated two peaks below 500 nm and then showed a downward trend. Among the two imaginary parts, the computed intensities of the FASnI$_3$ were higher than the MASnI$_3$ structures, corresponding to the largest absorption coefficient as displayed in Fig. 8(a). For the real parts of the FASnI$_3$, the absorption was nearly 5–7 eV, demonstrating that they had strong absorption in the ultraviolet spectrum. The second absorption was in the range of 9–10 eV in the calculated dielectric spectra. This absorption was basically located at the near ultraviolet spectrum. From the calculated dielectric spectra, the FASnI$_3$ had a good overlap with the MASnI$_3$ in both the imaginary and real parts. Thus, the FASnI$_3$ exhibited good solar energy absorption ability in the visible light spectrum.

4. Conclusions

In this study, we fabricated FASnI$_3$ and MASnI$_3$ perovskite solar cells and measured their PCE. The PCE of the FASnI$_3$ was 5.51%, higher than that of the MASnI$_3$. We used the SOC effect combined with the PBE function to analyze the structural, electronic, and optical properties of MASnI$_3$ and FASnI$_3$ perovskites. The results demonstrate that unlike the evident SOC effects in the FASnI$_3$ compared with the MASnI$_3$, the SOC affected the band length and band angle and reduced the organic cation radius, which both affected the equatorial and apical directions with a similar trend in the lattice parameters, changing the structure. The effect of the organic cation (FA$^+$) and inorganic framework was stronger in the FASnI$_3$ than in the MASnI$_3$, affecting the band length and band angle distribution and changing the structure of the FASnI$_3$ and MASnI$_3$. Based on
the analysis of the structural properties and the formation energies of the MASnI₃ and FASnI₃, it was clear that weak interactions between the cation FA⁺ or MA⁺ and the inorganic framework had an important effect on determining the equilibrium structures and the stabilities of the perovskites. In addition, the effective masses of the FASnI₃ had better electron and hole transport properties than the MASnI₃ under similar conditions. The optical properties and dielectric function of the FASnI₃ had a similar absorption ability to the MASnI₃. These results suggest that FASnI₃ may be a competitive and environmentally friendly alternative to MASnI₃ for efficient perovskite solar cells.

**Conflicts of interest**

There are no conflicts to declare.

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